# EL4332

Triple 2:1 300MHz Mux-Amp AV = 2

The EL4332 is a triple very high speed 2:1 Multiplexer-Amplifier. It is intended primarily for component video multiplexing and is especially suited for pixel switching. The amplifiers have their gain set to 2 internally, which reduces the need for many external components. The gain-of-2 facilitates driving back terminated cables. All three amplifiers are switched simultaneously from their A to B inputs by the TTL/CMOS compatible, common A/B control pin.

A -3dB bandwidth of 300MHz together with 3ns multiplexing time enable the full performance of the fastest component video systems to be realized.

The EL4332 runs from standard ±5V supplies, and is available in the narrow 16-pin small outline package.

Pinout

EL4332
[16-PIN SO (0.150")]
TOP VIEW
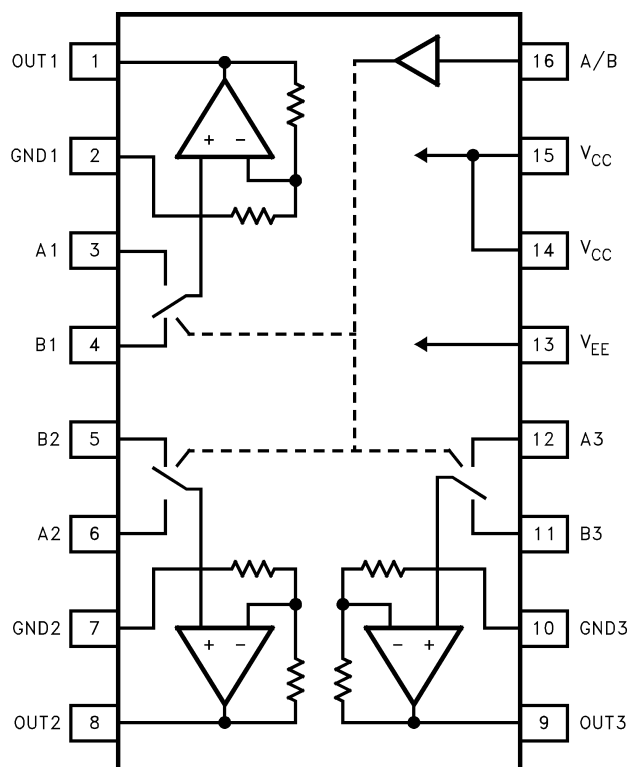
Features

- 3ns A-B switching
- 300MHz bandwidth
- Fixed gain of 2, for cable driving
- > 650V/μs slew rate
- TTL/CMOS compatible switch
- Pb-free available

Applications

- RGB multiplexing
- Picture-in-picture
- Cable driving
- HDTV processing
- Switched gain amplifiers
- ADC input multiplexer

Ordering Information

PART NUMBER	PACKAGE	TAPE & REEL	PKG. DWG. #
EL4332CS	16-Pin SO (0.150")	-	MDP0027
EL4332CS-T7	16-Pin SO (0.150")	7"	MDP0027
EL4332CS-T13	16-Pin SO (0.150")	13"	MDP0027
EL4332CSZ (Note)	16-Pin SO (0.150") (Pb-Free)	-	MDP0027
EL4332CSZ-T7 (Note)	16-Pin SO (0.150") (Pb-Free)	7"	MDP0027
EL4332CSZ-T13 (Note)	16-Pin SO (0.150") (Pb-Free)	13"	MDP0027

NOTE: Intersil Pb-free products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which is compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J Std-020B.

Demo Board

A demo PCB is available for this product.

Absolute Maximum Ratings (T$_A$ = 25°C)

V$_{CC}$ to V$_{EE}$ 14V
V$_{CC}$ to any GND 12V
V$_{EE}$ to any GND 12V
Continuous Output Current 45mA
Any Input . . . . V$_{EE}$ -0.3V to V$_{CC}$ +0.3V

Input Current, Any Input. 5mA
Power Dissipation . . . . See Curves
Ambient Operating Temperature . . . .-40°C to 85°C
Junction Temperature . . . . .150°C
Storage Temperature. . . . .-60°C to +150°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: T$_J$ = T$_C$ = T$_A$

DC Electrical Specifications   V$_{CC}$ = +5V, V$_{EE}$ = -5V, Temperature = 25°C, R$_L$ = ∞

PARAMETER	DESCRIPTION	MIN	TYP	MAX	UNITS
V$_{OS}$	Input Referred Offset Voltage		8	20	mV
dV$_{OS}$	Input Referred Offset Voltage Delta (Note 1)		2	8	mV
R$_{IN}$	Input Resistance		30		kΩ
I$_B$	Input Bias Current		-7	-30	µA
dI$_B$	Input Bias Current Delta (Note 1)		0.5	4.0	µA
A$_V$	Gain	1.94	2.00	2.06	V/V
dA$_V$	Gain Delta (Note 1)		0.5	2.5	%
C$_{IN}$	Input Capacitance		3.3		pF
PSRR	Power Supply Rejection Ratio	50	70		dB
V$_O$	Output Voltage Swing into 500Ω load	±2.7	±3.6		V
	Output Voltage Swing into 150Ω load		+3/-2.7		V
I$_{OUT}$	Current Output, Measured with 75Ω Load (Note 2)	30	40		mA
Xtalk$_{AB}$	Crosstalk from Non-selected Input (at DC)	-70	-100		dB
Xtalk$_{CH-CH}$	Crosstalk from one Amplifier to another Amplifier	-70	-100		dB
V$_{IH}$	Input Logic High Level	2.0			V
V$_{IL}$	Input Logic Low Level			0.8	V
I$_{IL}$	Logic Low Input Current (V$_{IN}$ = 0V)	-0.3	-40	-80	µA
I$_{IH}$	Logic High Input Current (V$_{IN}$ = 0V)	-3	0	3	µA
I$_S$	Total Supply Current	38	48	60	mA

NOTES:

1. Each channel's A-input to its B-input.

2. There is no short circuit protection on any output.

AC Electrical Specifications   V$_{CC}$ = +5V, V$_{EE}$ = -5V, Temperature = 25°C, R$_L$ = 150Ω, C$_L$ = 3pF.

| PARAMETER	DESCRIPTION	MIN	TYP	MAX	UNITS
BW	-3dB Bandwidth		300		MHz
BW 0.1dB	±0.1dB Bandwidth		105		MHz
DG	Differential Gain at 3.58MHz		0.04		%
DP	Differential Phase at 3.58MHz		0.08		°
Pkg	Peaking with Nominal Load		0.2		dB
SR	Slew Rate (4V Square Wave, Measured 25%–75%)		650		V/µs

AC Electrical Specifications V_{CC} = +5V, V_{EE} = -5V, Temperature = 25°C, R_L = 150Ω, C_L = 3pF. **(Continued)**

PARAMETER		DESCRIPTION	MIN	TYP	MAX	UNITS
t_S		Settling Time to 0.1% of Final Value		13		ns
T_{SW}		Time to Switch Inputs		3		ns
OS		Overshoot, V_{OUT} = 4V_{P-P}		8		%
I_{SO}ab	10M	Input to Input Isolation at 10MHz		60		dB
	100M	Input to Input Isolation at 100MHz		40		dB
I_{SO}ch-ch	10M	Channel to Channel Isolation at 10MHz		61		dB
	100M	Channel to Channel Isolation at 100MHz		50		dB

Pin Descriptions

PIN NAME	FUNCTION
A1, A2, A3	"A" inputs to amplifiers 1, 2 and 3 respectively.
B1, B2, B3	"B" inputs to amplifiers 1, 2 and 3 respectively.
GND1, GND2, GND3	These are the individual ground pins for each channel.
Out1, Out2, Out3	Amplifier outputs. Note: there is no short circuit protection on any output.
V_{CC}	Positive power supply. Typically +5V.
V_{EE}	Negative power supply. Typically -5V.
A/B	Common input select pin, a logic high selects the "A" inputs, logic low selects the "B" inputs. CMOS/TTL compatible.

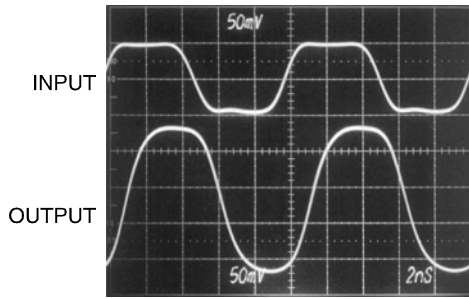## *Burn In Schematic*
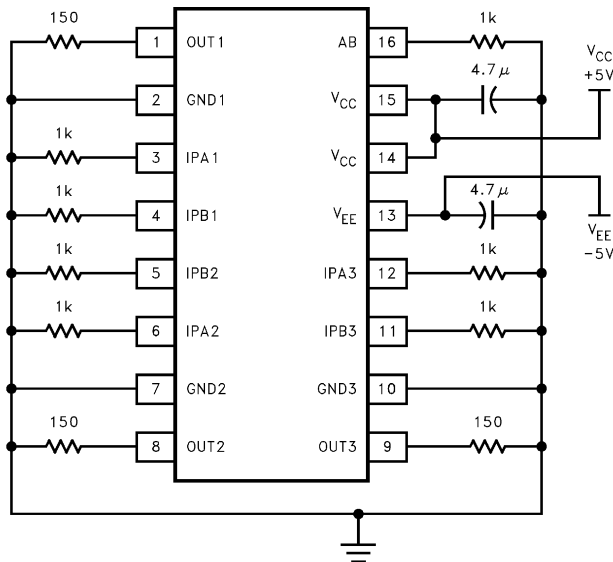
Typical Performance Curves
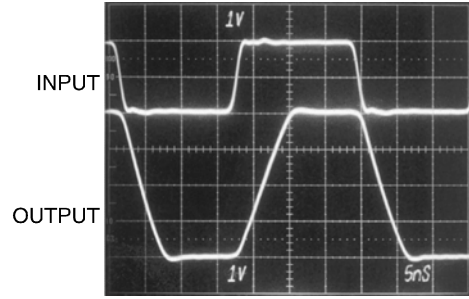
FIGURE 1. SMALL SIGNAL TRANSIENT RESPONSE

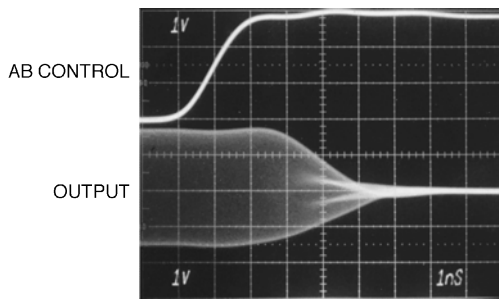FIGURE 2. LARGE SIGNAL TRANSIENT RESPONSE

FIGURE 3. SWITCHING TO GROUND FROM A LARGE
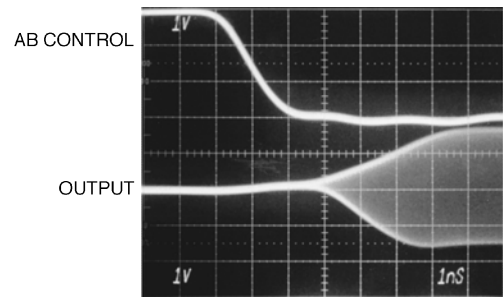SIGNAL UNCORRELATED SINE WAVE

FIGURE 4. SWITCHING FROM GROUND TO A LARGE
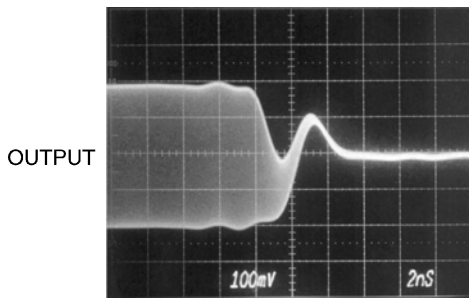SIGNAL UNCORRELATED SINE WAVE

FIGURE 5. SWITCHING TO GROUND FROM A SMALL
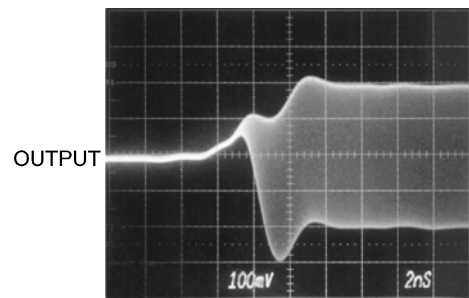SIGNAL UNCORRELATED SINE WAVE

FIGURE 6. SWITCHING FROM GROUND TO A SMALL
SIGNAL UNCORRELATED SINE WAVE
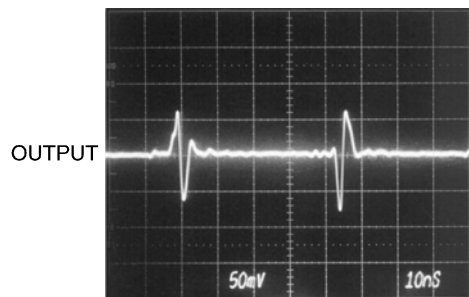
FIGURE 7. SWITCHING GLITCH (INPUTS AT GROUND)
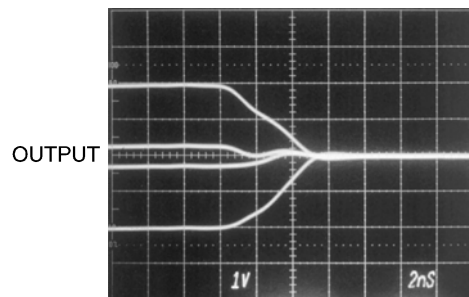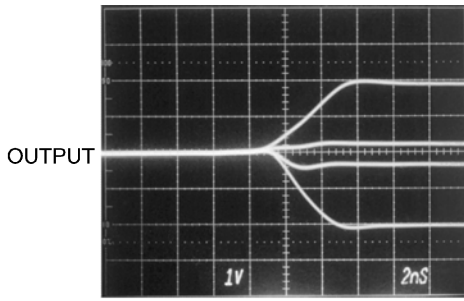
FIGURE 8. SWITCHING FROM A FAMILY OF DC LEVELS TO
GROUND

Typical Performance Curves (Continued)

FIGURE 9. SWITCHING FROM GROUND TO A FAMILY OF DC LEVELS
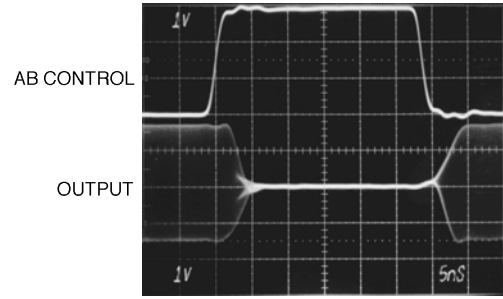
FIGURE 10. CHANNEL A/B SWITCHING DELAY
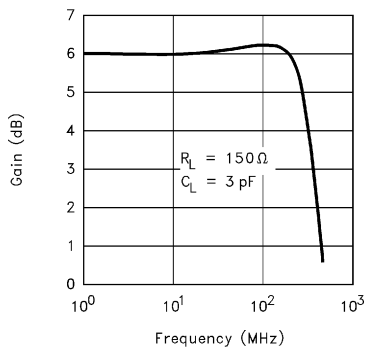
FIGURE 11. GAIN vs FREQUENCY
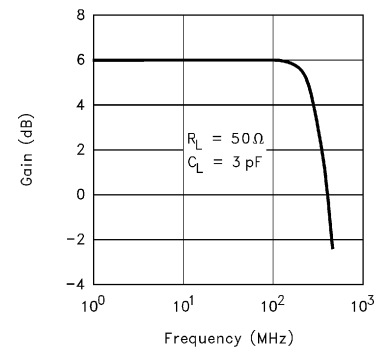
FIGURE 12. GAIN vs FREQUENCY
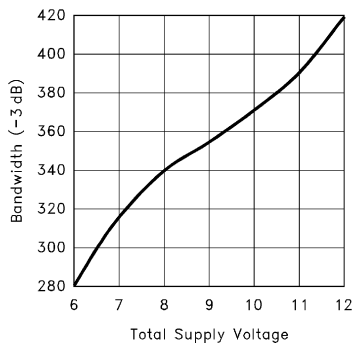
FIGURE 13. -3dB BW vs SUPPLY VOLTAGE
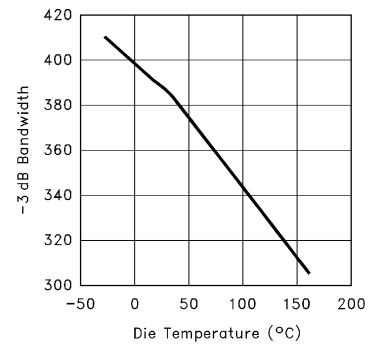
FIGURE 14. BANDWIDTH vs DIE TEMPERATURE

Typical Performance Curves (Continued)
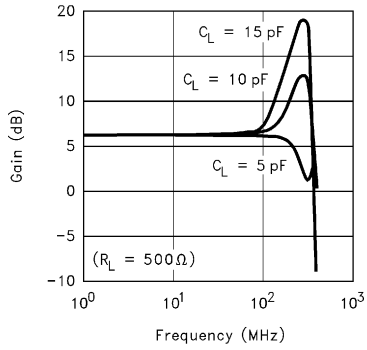
FIGURE 15. FREQUENCY RESPONSE WITH CAPACITIVE LOADS
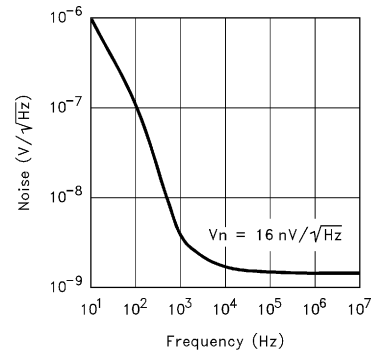
FIGURE 16. INPUT VOLTAGE NOISE OVER FREQUENCY
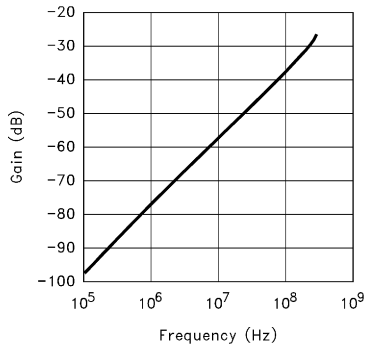
FIGURE 17. A-INPUT TO B–INPUT ISOLATION
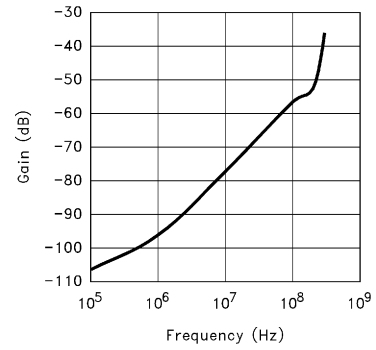
FIGURE 18. CHANNEL-CHANNEL ISOLATION
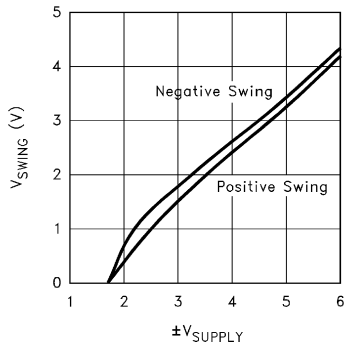
FIGURE 19. OUTPUT SWING vs SUPPLY VOLTAGE
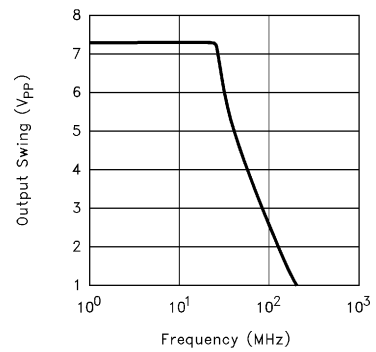
FIGURE 20. OUTPUT SWING vs FREQUENCY

Typical Performance Curves (Continued)
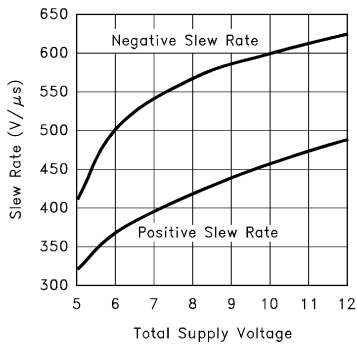
FIGURE 21. SLEW RATE vs SUPPLY VOLTAGE
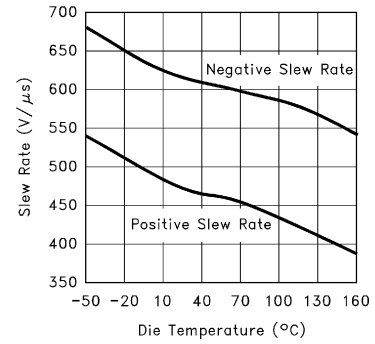
FIGURE 22. SLEW RATE vs DIE TEMPERATURE
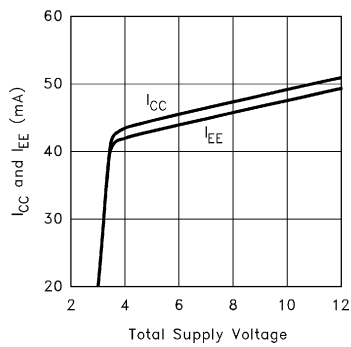
FIGURE 23. SUPPLY CURRENT vs SUPPLY VOLTAGE
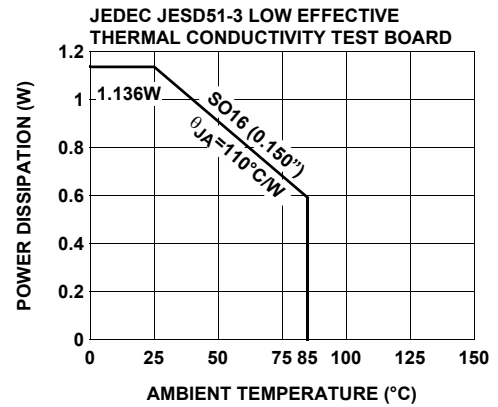
FIGURE 24. POWER DISSIPATION vs AMBIENT TEMPERATURE
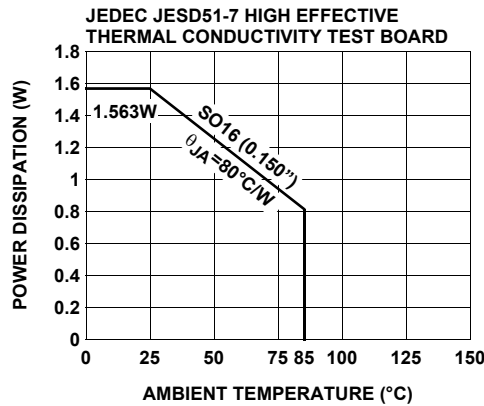
FIGURE 25. POWER DISSIPATION vs AMBIENT TEMPERATURE
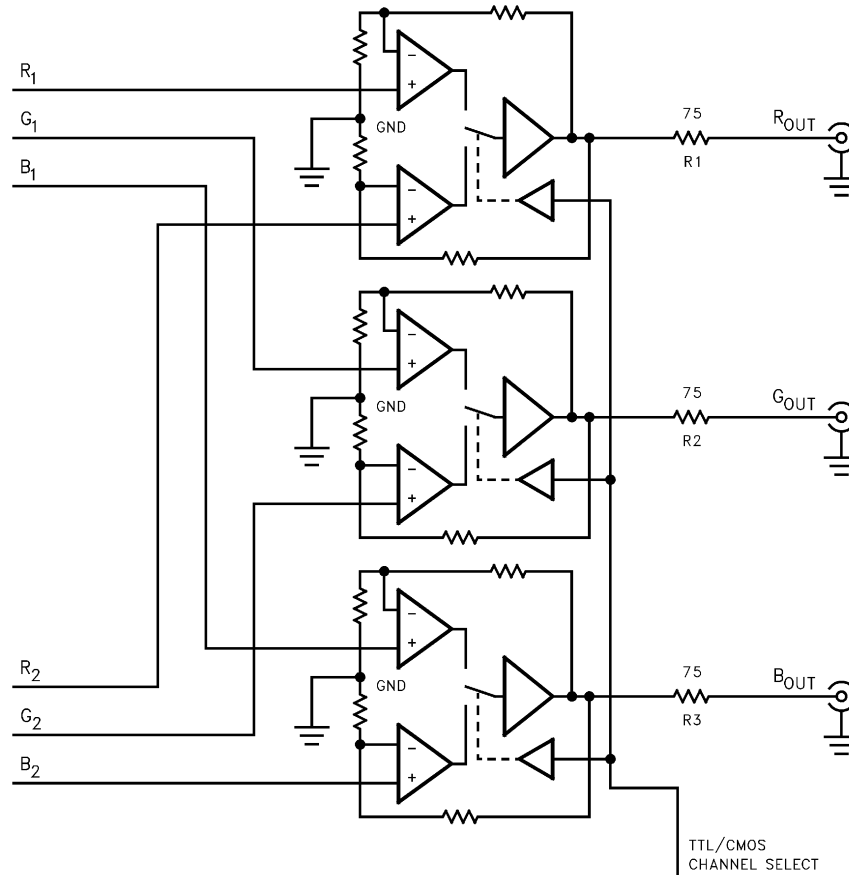
FIGURE 26. TYPICAL CONNECTION FOR A 2:1 COMPONENT VIDEO MULTIPLEXER

Applications Information

Figure 26 shows a typical use for the EL4332. The circuit is a component video (R,G, B or Y,U,V) multiplexer. Since the gain of the internal amplifiers has been set to 2, the only extra components needed are the supply decoupling capacitors and the back terminating resistors, if transmission lines are to be driven. The EL4332 can drive backmatched 50Ω or 75Ω loads.

Grounds

It will be noticed that each mux-amp channel has its own separate ground pin. These ground pins have been kept separate to keep the channel separation inside the chip as large as possible. The feedback resistors use these ground pins as their reference. The resistors total 400Ω, so there is a significant signal current flowing from these pins to ground.

The ground pins should all be connected together, to a ground plane underneath the chip. 1 oz. copper for the ground plane is highly recommended.

Further notes and recommended practices for high speed printed circuit board layout can be found in the tutorials in the Elantec databooks.

Supplies

Supply bypassing should be as physically near the power pins as possible. Chip capacitors should be used to minimize lead inductance. Note that larger values of capacitor tend to have larger internal inductances. So when designing for 3 transmission lines or similar moderate loads, a 0.1µF ceramic capacitor right next to the power pin in parallel with a 22µF tantalum capacitor placed as close to the 0.1µF is recommended. For lighter loadings, or if not all the channels are being used, a single 4.7µF capacitor has been found quite adequate.

Note that component video signals do tend to have a high level of signal correlation. This is especially true if the video signal has been derived from 3 synchronously clocked DACs. This corresponds to all three channels drawing large slew currents simultaneously from the supplies. Thus, proper bypassing is critical.

Logic Inputs

The A/B select, logic input, is internally referenced to ground. It is set at 2 diode drops above ground, to give a threshold of about 1.4V (see Figure 27). The PNP input transistor requires that the driving gate be able to sink current, typically < 30µA, for a logic "low". If left to float, it will be a logic "high".
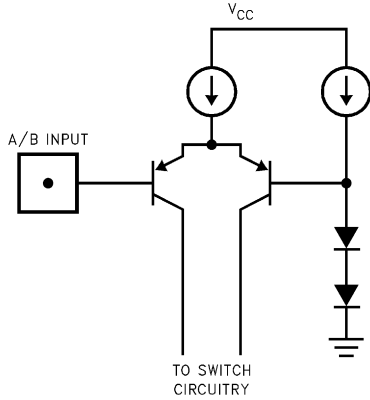
FIGURE 27. SIMPLIFIED LOGIC INPUT STAGE

The input PNP transistors have sufficient gain that a simple level shift circuit (see Figure 28) can be used to provide a simple interface with Emitter Coupled Logic. Typically, 200mV is enough to switch from a solid logic "low" to a "high."
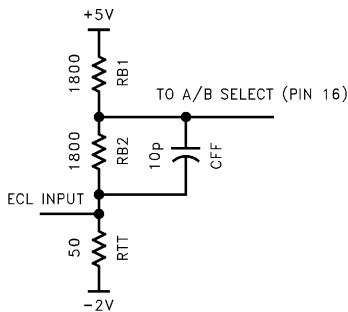
**FIGURE 28. ADAPTING THE SELECT PIN
FOR ECL LOGIC LEVELS**

The capacitor C_{FF} is only in the network to prevent the A/B pin's capacitance from slowing the control signal. The network shown level shifts the ECL levels, -0.7V to -1.5V to +1.6V and +1.1V respectively. The terminating resistor, R_{TT}, is required since the open emitter of the ECL gate can not sink current. If a -2V rail is not being used, a 220Ω to 330Ω resistor to the -5.2V rail would have the same effect.

Expanding the Multiplexer

In Figure 29, a 3:1 multiplexer circuit is shown. The expansion to more inputs is very straight forward. Since the EL4332 has a fixed gain of 2, interstage attenuators may be required as shown in Figure 28. The truth table for the 3:1 multiplexer select lines is:

TABLE 1.

X	Y	MUX OUTPUT
0	0	R3, G3, B3
0	1	R2, G2, B2
1	X	R1, G1, B1

When interstage attenuators are used, the values should be kept down in the region of 50Ω–300Ω. This is to prevent a combination of circuit board stray capacitance and the EL4332's input capacitance forming a significant pole. For example, if instead of 100Ω as shown, resistors of 1kΩ had been used, and assuming 3pF of stray and 3pF of input capacitance, a pole would be formed at about 53MHz.
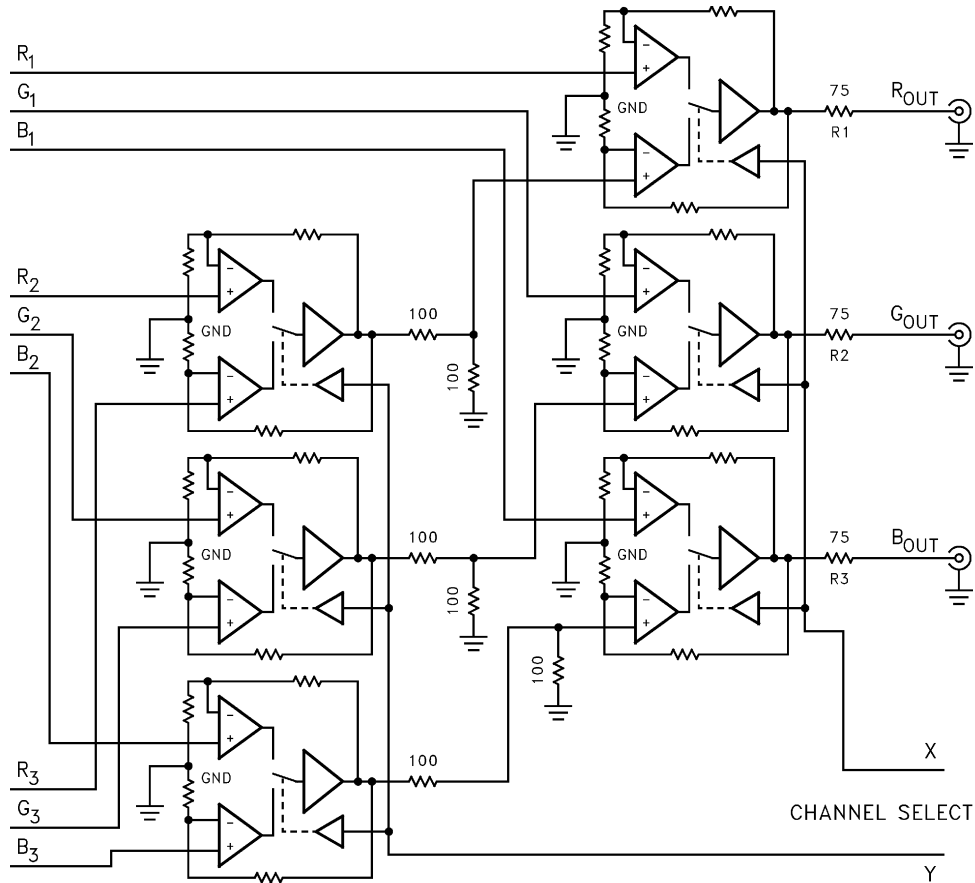
FIGURE 29. TYPICAL CONNECTION FOR A 3:1 COMPONENT VIDEO MULTIPLEXER

A Bandwidth Selectable Circuit

In Figure 30, a circuit is shown that allows three signals to be either low pass filtered or full bandwidth.

This could be useful where an input signal is frequently noisy. The component values shown give a Butterworth LPF response, with a -3dB frequency of 50MHz. Note again, the resistor values are low, so that stray capacitance does not affect the desired cut-off frequency.
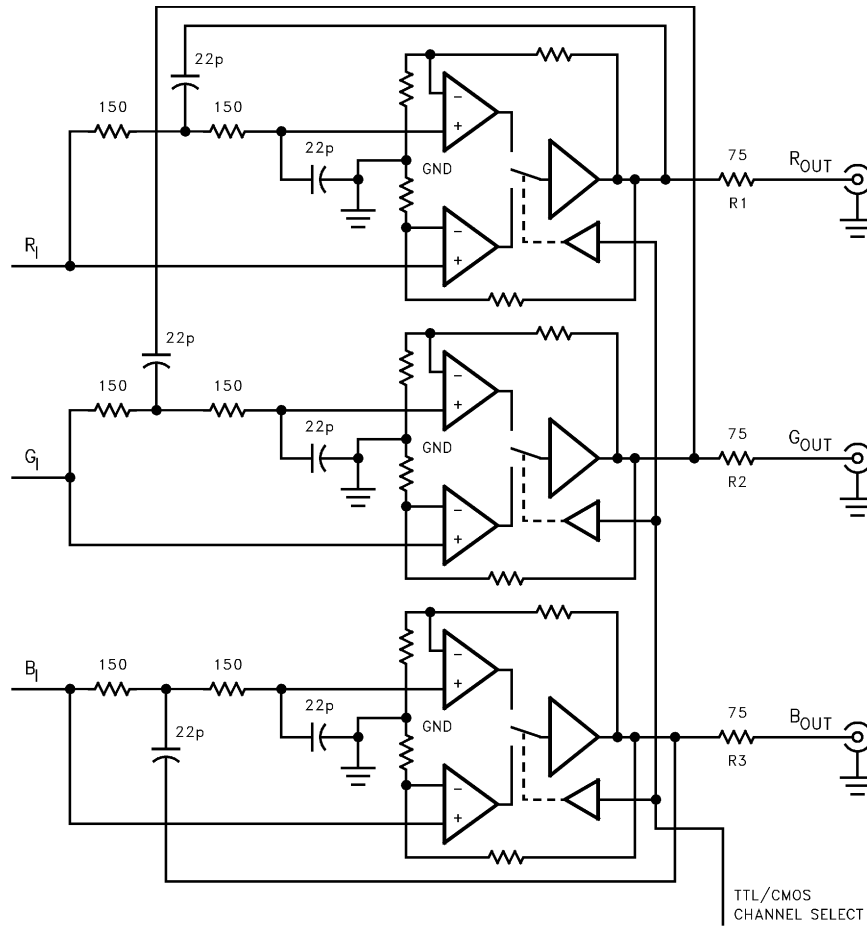
FIGURE 30. SWITCHED 50MHz LOW PASS FILTER FOR HIGH/LOW RESOLUTION MONITORS

EL4332 Macromodel

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* EL4332 Macromodel
* Revision A, April 1996
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*Applications Hints. The EL4332 has two V_{CC} pins, one V_{EE} pin, and three ground
*pins. The V_{CC} pins (pins 14 and 15 are internally shorted together in the model,
*but the ground pins (GND1, GND2, and GND3 (nodes 2, 7, and 10, respectively)
*must be connected to ground (node 0) using a le-6W resistor. Alternatively,
* nodes 2, 7, and 10 may be connected to ground through a 25Ω resistor in parallel
* with a 4nH inductor to simulate package and PCB parasitics.
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```
* Connections:
*   OUT1
*   |   GND1
*   |   |   A1
*   |   |   |   B1
*   |   |   |   |   B2
*   |   |   |   |   |   A2
*   |   |   |   |   |   |   GND2
*   |   |   |   |   |   |   |   OUT2
*   |   |   |   |   |   |   |   |
*   |   |   |   |   |   |   |   |
*   1   2   3   4   5   6   7   8
*
*   OUT3
*   |   GND3
*   |   |   B3
*   |   |   |   A3
*   |   |   |   |   VEE
*   |   |   |   |   |   VCC
*   |   |   |   |   |   |   VCC
*   |   |   |   |   |   |   |   A/B
*   |   |   |   |   |   |   |   |
*   |   |   |   |   |   |   |   |
*   9   10  11  12  13  14  15  16
************A B Switch ***************
Rshort 14 15 le-12
rshort1 15 0 100 Meg
Isw 14 110 1.5 mA
vref 111 0 1.6V
q1 101 16 110 qp
q2 102 111 110 qp
R1 101 13 500
R2 102 13 500
Rd1 107 0 100
Esw 107 0 table {v(102, 101)*100} (0,0) (1,1)
*
************Amplifier #1 *************
q131 103 3 112 qp
q141 104 114 113 qp
q151 105 4 115 qp
q161 106 117 116 qp
Ia11 14 112 1 mA
Ia21 14 113 1 mA
Ib11 14 115 1 mA
Ib21 14 116 1 mA
Rga1 112 113 275
Rgb1 115 116 275
R31 103 13 275
R41 104 13 275
```

R51 105 13 275
R61 106 13 275
R71 1 114 400
R81 114 2 400
R911 117 400
R110 117 2 400
Ediff1 108 0 value {(v(104,103)*v(107))+(v(106,105)*(1-v(107)))}
rdiff1 108 0 1K
*
*Compensation Section
*
ga1 0 134 108 0 1m
rh1 134 0 5 Meg
cc1 134 0 0.6 pF
*
*Poles
*
ep1 141 0 134 0 1.0
rpa1 141 142 200
cpa1 142 0 0.75 pF
rpb1 142 143 200
cpb1 143 0 0.75 pF
*
*Output Stage
*
i011 15 150 1.0 mA
i021 151 13 1.0 mA
q71 13 143 150 qp
q81 15 143 151 qn
q91 15 150 152 qn
q101 13 151 153 qp
ros11 152 1 2
ros21 153 1 2
*
************Amplifier #2***********
q231 203 6 212 qp
q241 204 214 213 qp
q251 205 5 215 qp
q261 206 217 216 qp
la12 14 212 1 mA
la22 14 213 1 mA
lb12 14 215 1 mA
lb22 14 216 1 mA
Rga2 212 213 275
Rgb2 215 216 275
R231 203 13 275
R241 204 13 275
R251 205 13 275
R261 206 13 275
R271 8 214 400
R281 214 7 400
R291 8 217 400
R210 217 7 400
Ediff2 208 0 value {(v(204,203)*v(107))+(v(206,205)*(1-v(107)))}
rdiff2 208 0 1K
*
* Compensation Section
*
ga2 0 234 208 0 1m
rh2 234 0 5 Meg
cc2 234 0 0.6 pF

```
*
* Poles
*
ep2 241 0 234 0 1.0
rpa2 241 242 200
cpa2 242 0 0.75 pF
rpb2 242 243 200
cpb2 243 0 0.75 pF
*
*Output Stage
*
i0 12 15 250 1.0 mA
i022 251 13 1.0 mA
q271 13 243 250 qp
q281 15 243 251 qn
q291 15 250 252 qn
q201 13 251 253 qp
ros12 252 8 2
ros22 253 8 2
*
************Amplifier #3 ************
q331 303 12 312 qp
q341 304 314 313 qp
q351 305 11 315 qp
q361 306 317 316 qp
la13 14 312 1 mA
la23 14 313 1 mA
lb13 14 315 1 mA
lb23 14 316 1 mA
Rga3 312 313 275
Rgb3 315 316 275
R331 303 13 275
R341 304 13 275
R351 305 13 275
R361 306 13 275
R371 9 314 400
R381 314 10 400
R391 9 317 400
R310 317 10 400
Ediff3 308 0 value {( v(304,303)*(v(107))+(v(306,305)*(1-v(107)))}
rdiff3 308 0 1K
*
* Compensation
*
ga3 0 334 308 01m
rh3 334 0 5 Meg
cc3 334 0 0.6 pF
*
* Poles
*
ep3 341 0 3340 1.0
rpa3 341 342 200
cpa3 342 0 0.75 pF
rpb3 342 343 200
cpb3 343 0 0.75 pF
*
* Output Stage
*
i013 15 350 1.0 mA
i023 351 13 1.0 mA
q371 13 343 350 qp
```

```
q381 15 343 351 qn
q391 15 350 352 qn
q301 13 351 353 qp
ros13 352 9 2
ros23 353 9 2
*
* Power Supply Current
*
ips 15 13 22 mA
*
*Models
*
.model qp pnp(is=1.5e-16 bf=300 tf=0.01 ns)
.model qn npn(is=0.8e-18 bf=300 tf=0.01 ns)
.ends
```

For additional products, see www.intersil.com/en/products.html

Intersil products are manufactured, assembled and tested utilizing ISO9001 quality systems as noted
in the quality certifications found at www.intersil.com/en/support/qualandreliability.html

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